



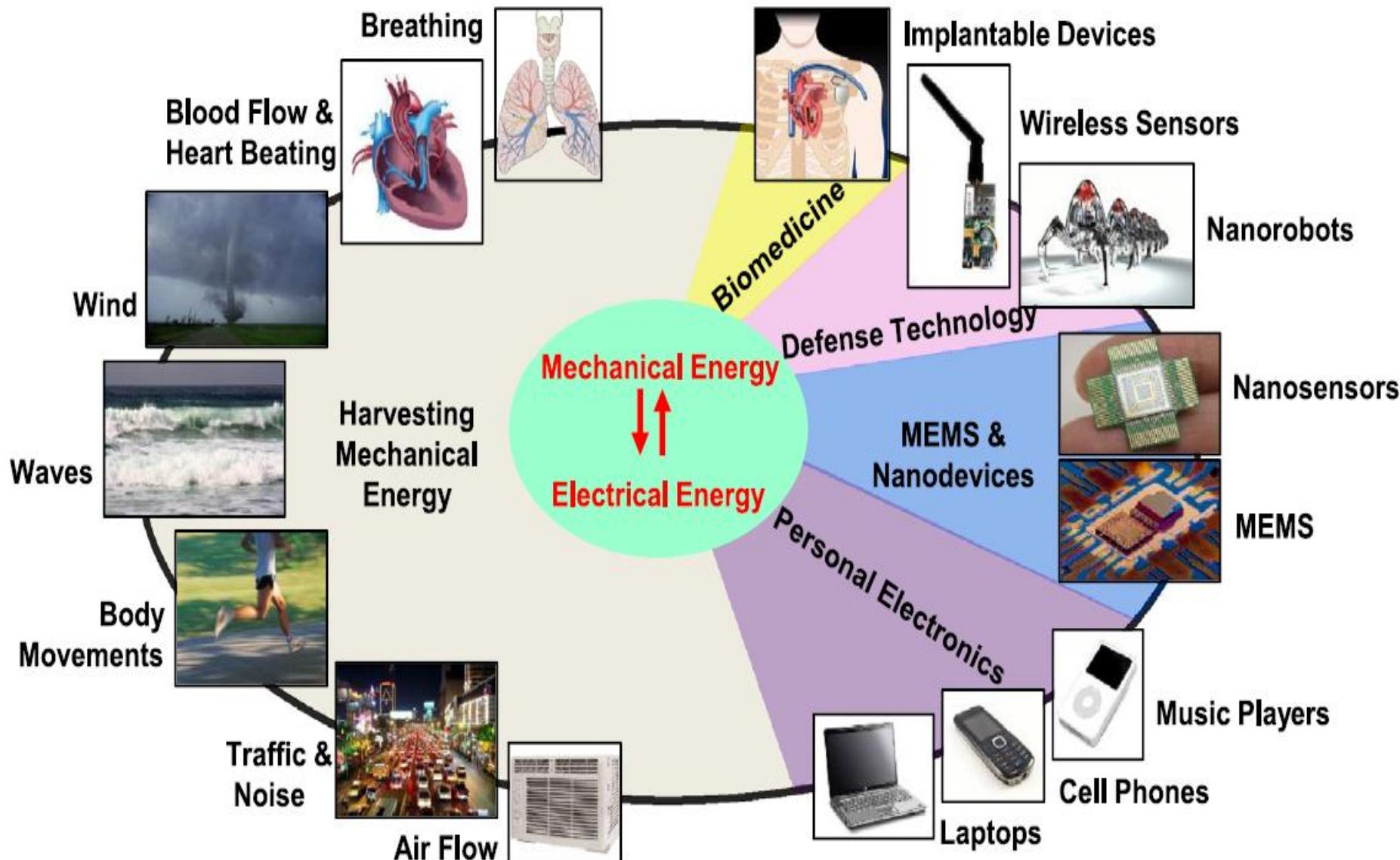
The ASEAN on Thermoelectric Device Workshop 2018

เทคโนโลยีพิโซอิเล็กทริก
ประโยชน์จากการผลั้งงานกล

ดร. บรรษัท วรรธนะสาร

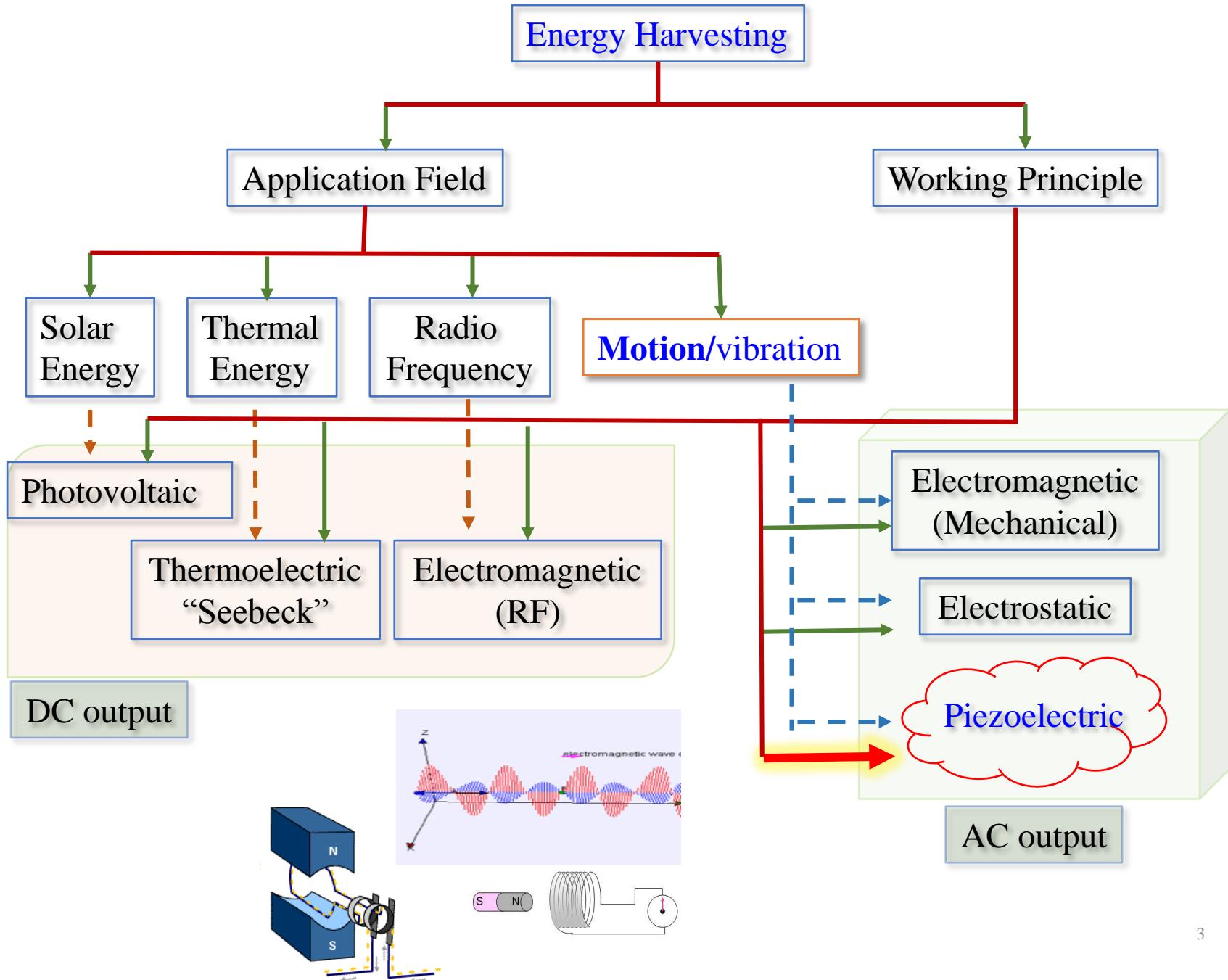
สาขาวิชาพิสิกส์ คณะวิทยาศาสตร์และเทคโนโลยี

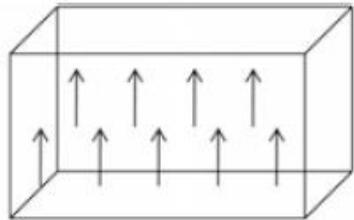




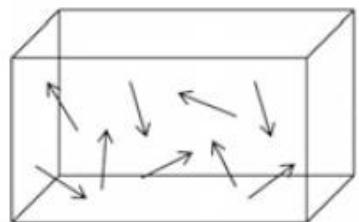
Possible sources of energy for harvesting (left) and opportunities use of this energy in sensing and actuation (right) that can be considered for flexible/bendable devices.

Main energy harvesting technologies.

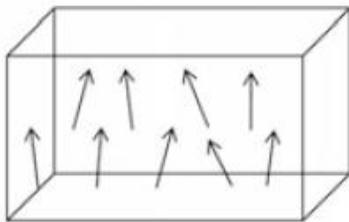




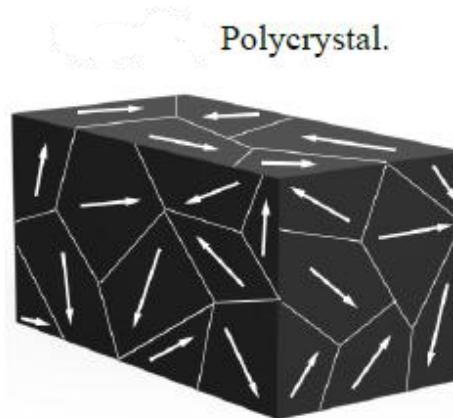
monocrystal



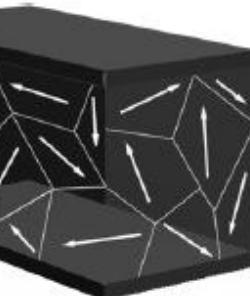
polycrystal



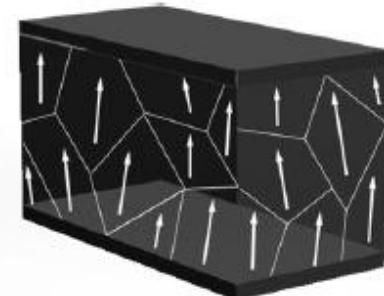
polycrystal after polarization



Polycrystal.



(a)

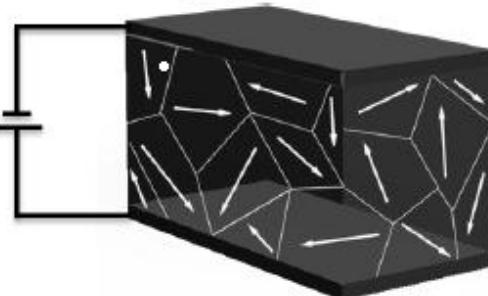


(b)

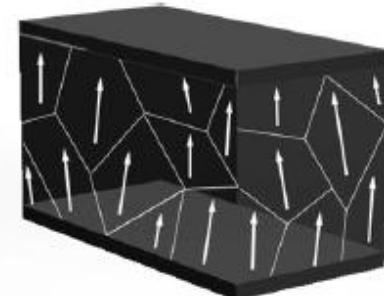
Dipoles are well aligned in monocrystal, but random in polycrystal.

The dipoles in polycrystal can be aligned through polarization

(a) Polarizations; (b) Surviving Polarity.

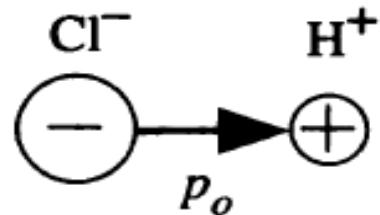


(a)

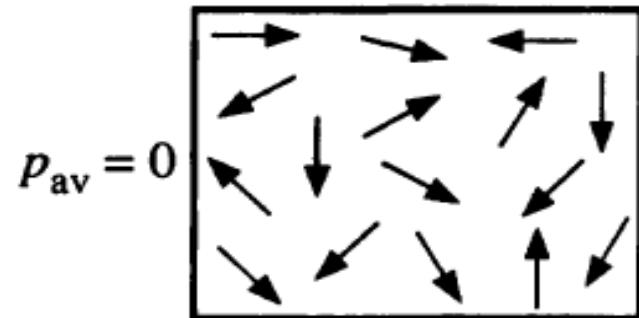


(b)

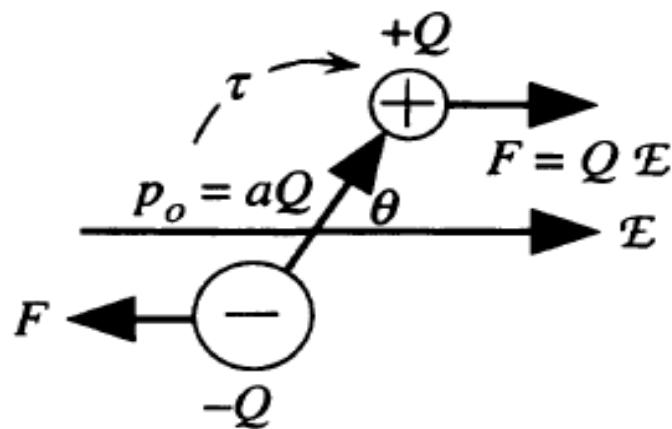
Dipole



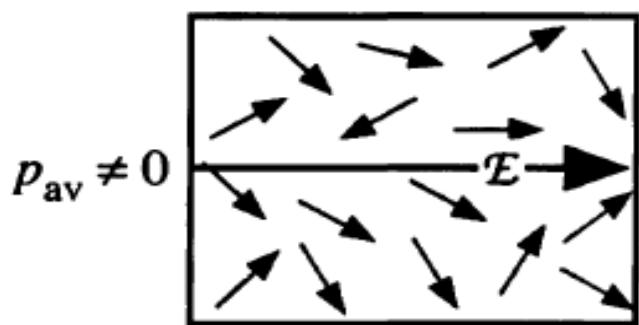
(a)



(b)

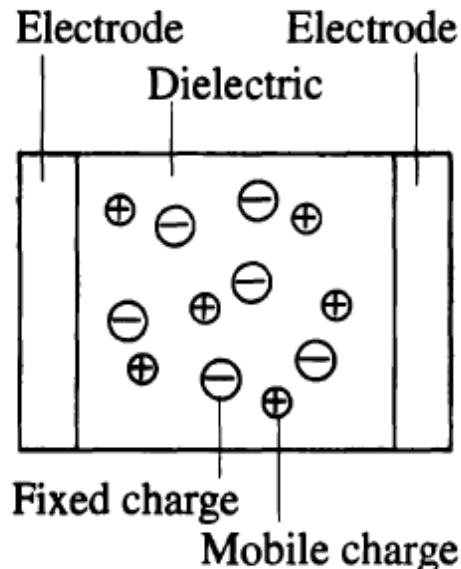


(c)

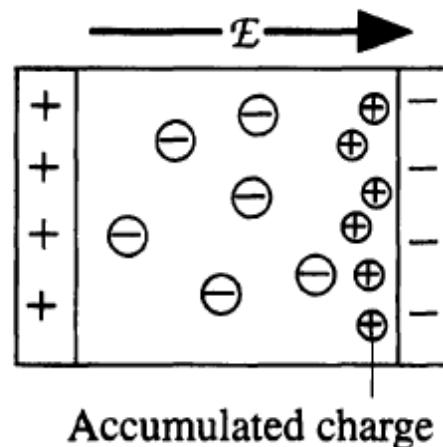


(d)

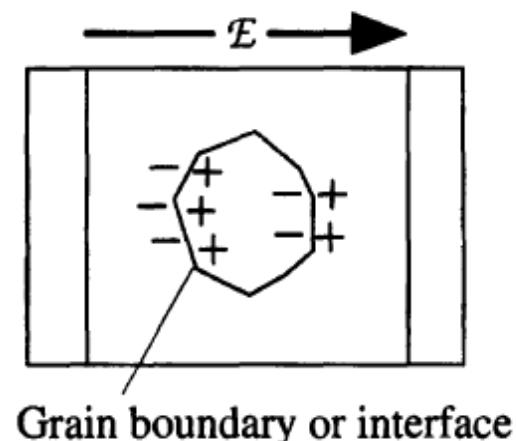
Dielectric material



(a)



(b)



(c)

- (a) A crystal with equal number of mobile positive ions and fixed negative ions. In the absence of a field, there is no net separation between all the positive charges and all negative charges.
- (b) In the presence of and applied field, the mobile positive ions migrate toward the negative charges and positive charges in the dielectric. The dielectric therefore exhibits interfacial polarization.
- (c) Grain boundaries and interface between different materials frequently give rise to interfacial polarization.

$$C = \frac{\epsilon_0 \epsilon_r A}{t}$$

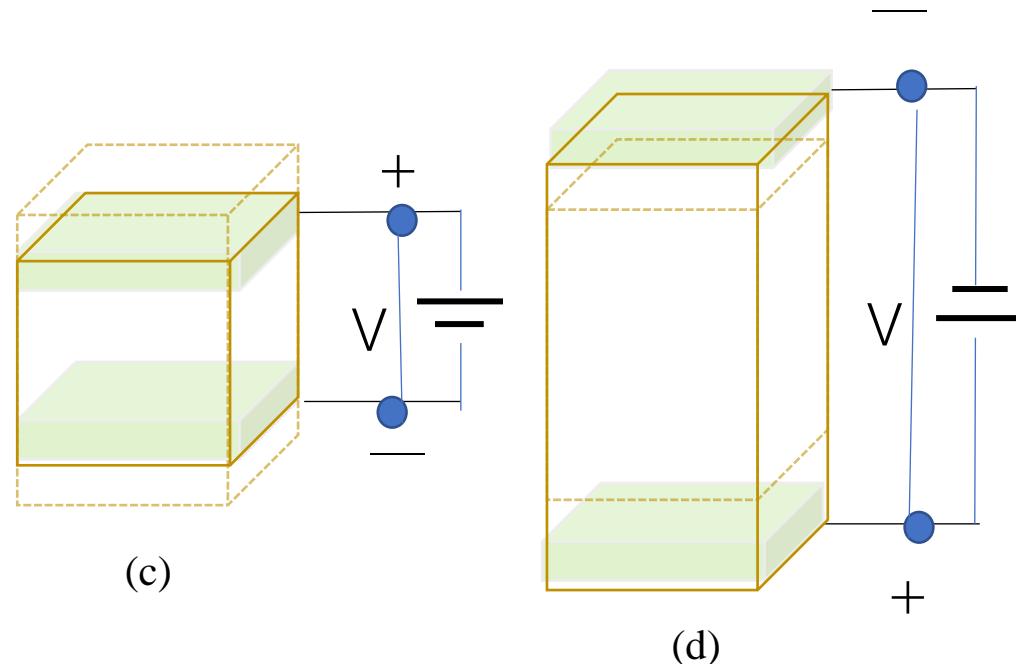
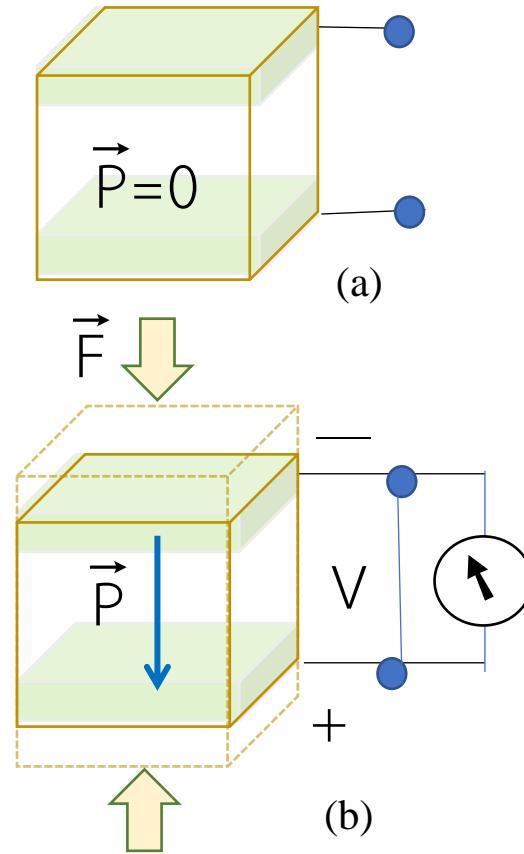
ϵ_r the relative permittivity or dielectric constant

ϵ_0 the vacuum permittivity

A the area

t the thickness

C the capacitance



The piezoelectric effect

- (a) A piezoelectric crystal with no applied stress or field
- (b) The crystal is strained by applied force that induces polarization in the crystal and generates surface charges
- (c) An applied field causes the crystal to become strained. In this case the field compresses the crystal
- (d) The strain changes direction with the applied field and now the crystal is extended

Electromechanical coupling factor k

direct piezoelectric effect

$$P_i = d_{ij} X_j$$

converse piezoelectric effect

$$X_j = d_{ij} E_j$$

$$i = 1, 2, 3; \quad j = 1, 2, \dots, 6$$

$$g = \frac{d}{\epsilon_r}$$

P_i the induce polarization along some i direction

X_j the applied mechanical stress along some j direction

d_{ij} the piezoelectric coefficients

S_j the induce strain

E_i the applied electric field

g the piezoelectric voltage constant

f_s the resonant frequency f_a antiresonant frequency

$$k^2 = \frac{\text{Electrical energy converted to mechanical energy}}{\text{Input of electrical energy}}$$

$$k^2 = \frac{\text{Electrical energy converted to electrical energy}}{\text{Input of mechanical energy}}$$

$$k^2 = 1 - \frac{f_s^2}{f_a^2}$$

The efficiency of energy conversion,

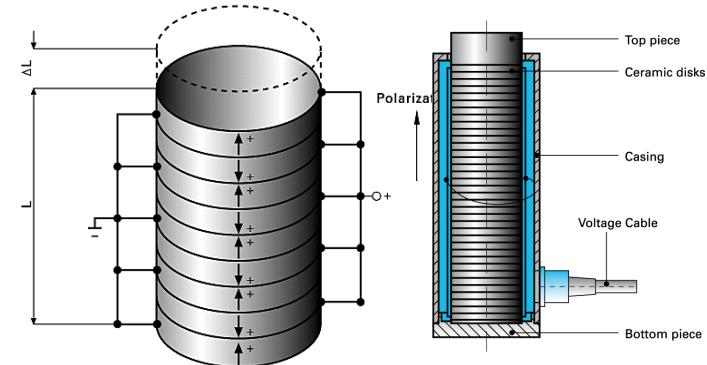
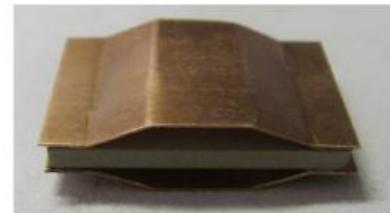
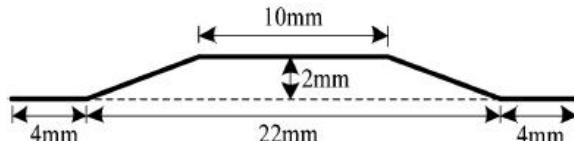
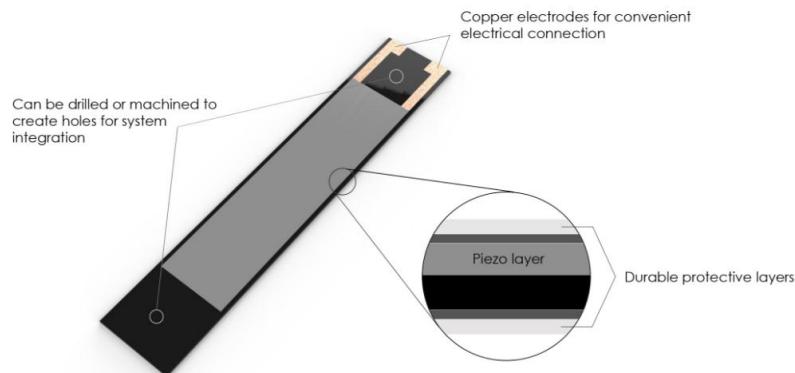
$$\text{efficiency } \eta = \frac{Q k^2}{(1 - k^2) + Q k^2}$$

Mechanical quality factor, Q_m

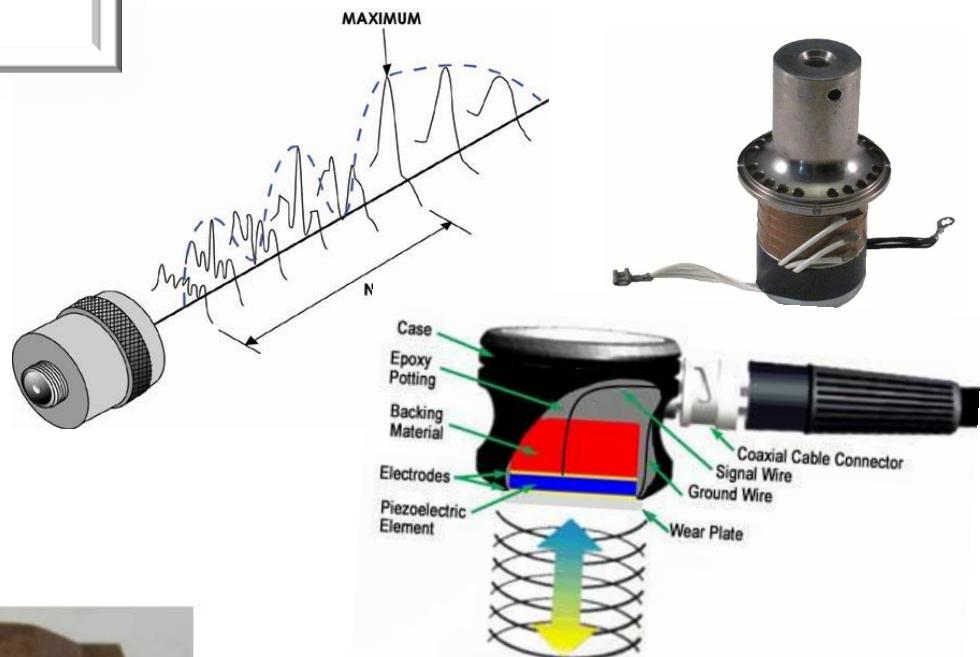
$$Q = \frac{1}{2\pi \Delta f RC}$$

PRELOADED

Piezoelectric monomorph



Piezoelectric actuator



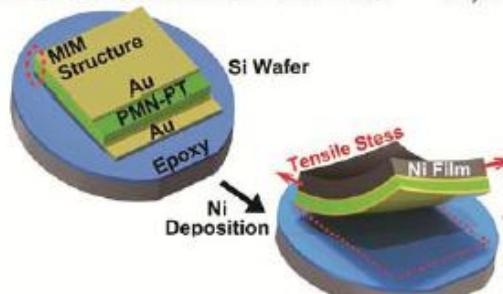
Piezoelectric transducer

<http://www.ultrasonic>

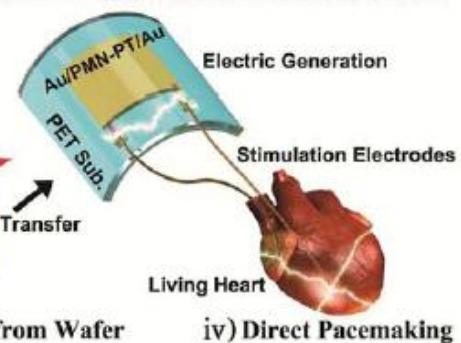
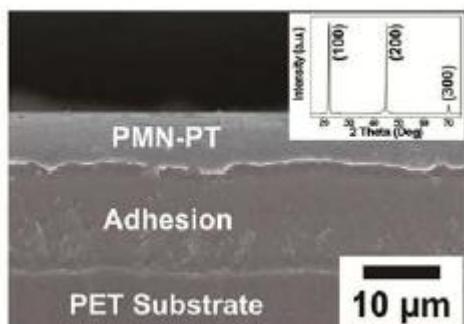
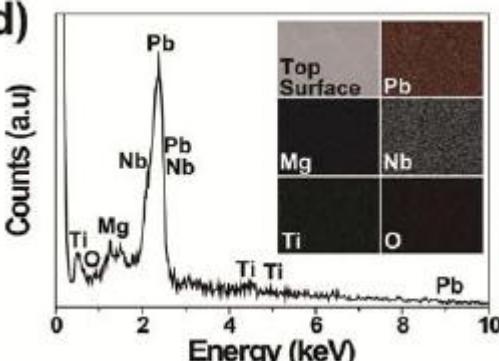
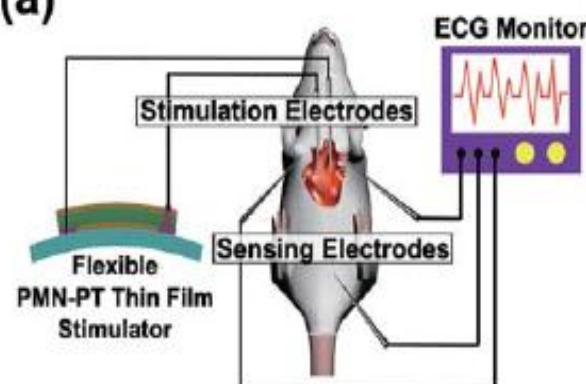
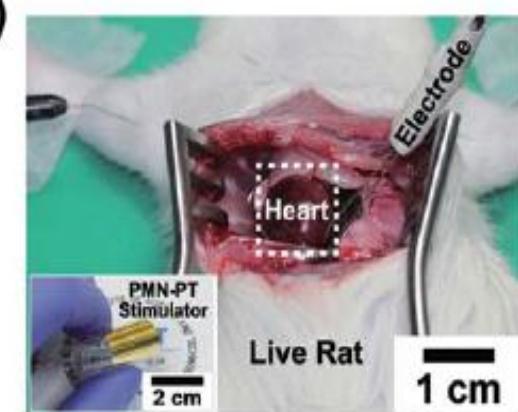
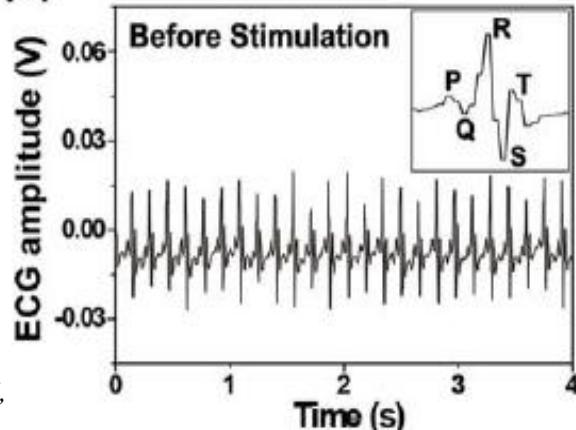
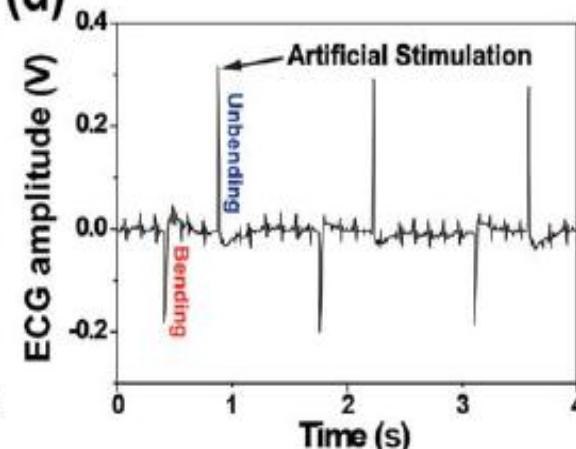
resonators.org/design/transducers/transducer_design.html
<https://www.ndeed.org/EducationResources/CommunityCollege/Ultrasonics/EquipmentTrans/characteristicspt.htm>

(a)

i) PMN-PT Thin Film on Bulk Wafer



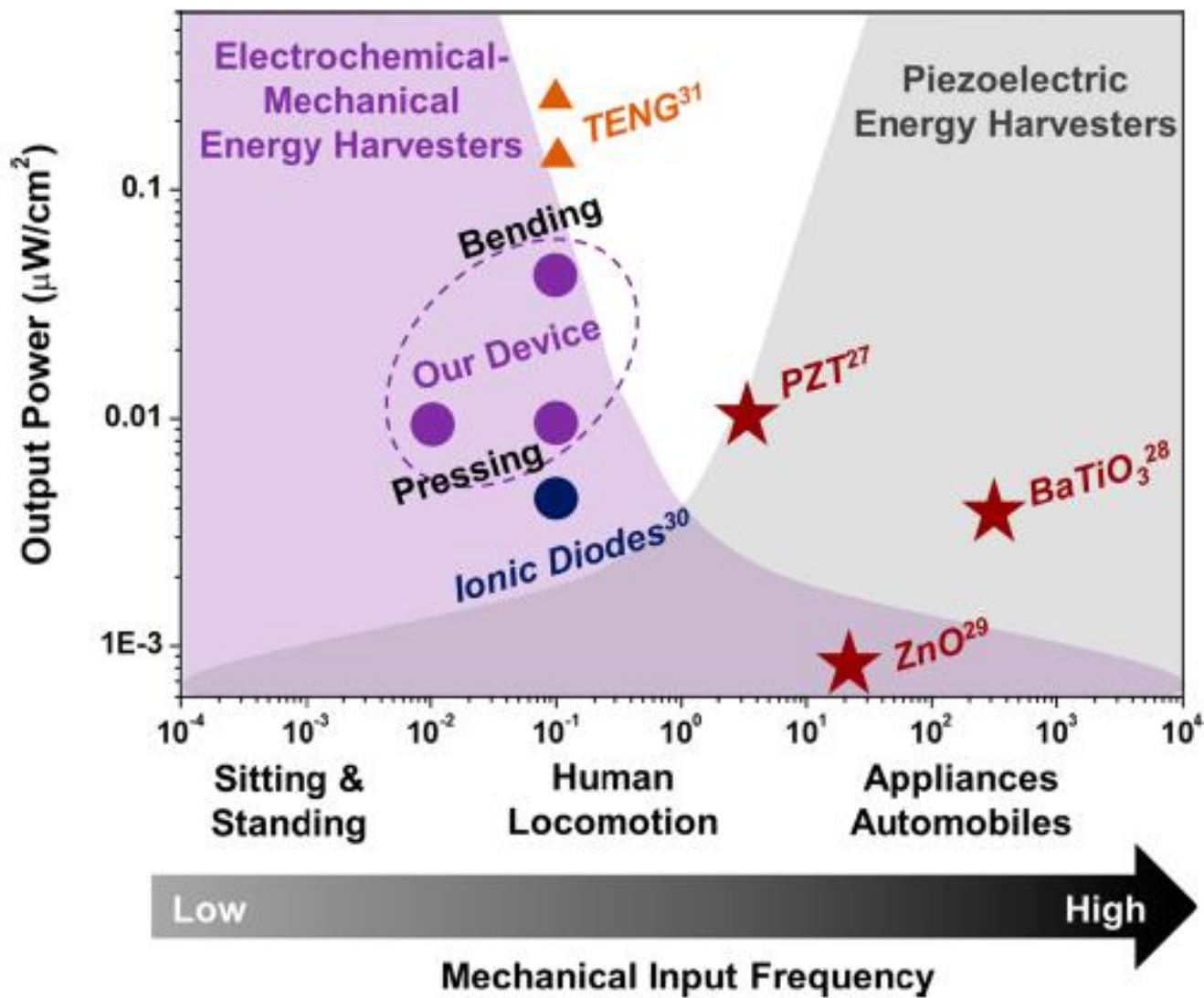
iii) PMN-PT Thin Film on Flexible Substrate

**(b)****(d)****(a)****(b)****(c)****(d)****(e)**

Flexible Energy Harvester

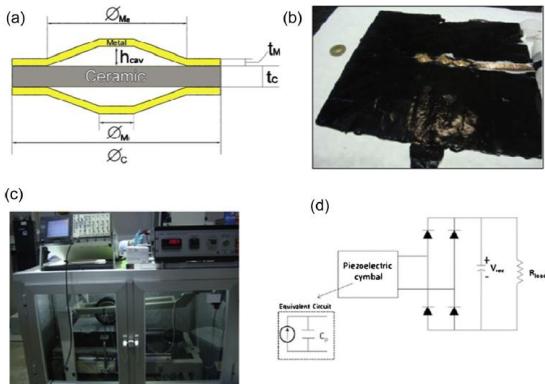


Geon-Tae Hwang, Hyewon Park, Jeong-Ho Lee, SeKwon Oh, Kwi-Il Park, Myunghwan Byun, Hyelim Park, Gun Ahn, Chang Kyu Jeong, Kwangsoo No, HyukSang Kwon, Sang-Goo Lee, Boyoung Joung, and Keon Jae Lee. Self-Powered Cardiac Pacemaker Enabled by Flexible Single Crystalline PMN-PT Piezoelectric Energy Harvester. *Adv. Mater.* 2014, 26, 4880–4887

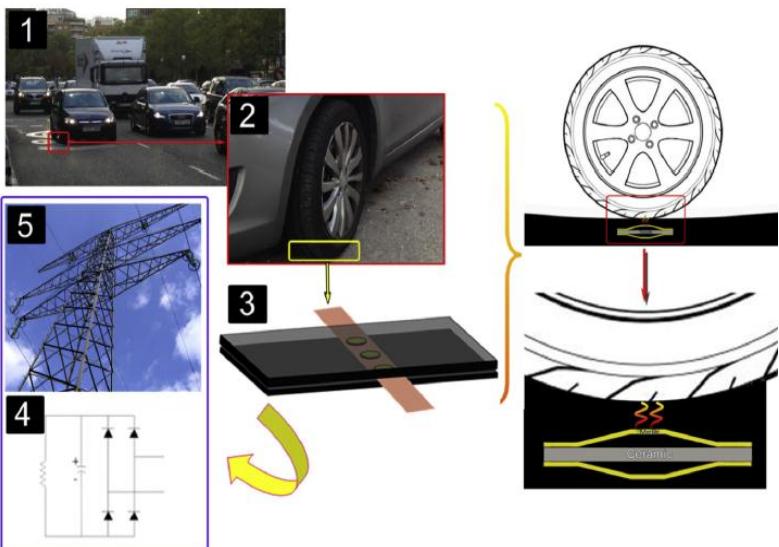


Shaded regions indicate the fall-off of **energy harvesting capability at low frequencies outside of the range of traditional harvesting routes (left)** and **at high frequencies outside of the range of electrochemical harvesters (right)**.





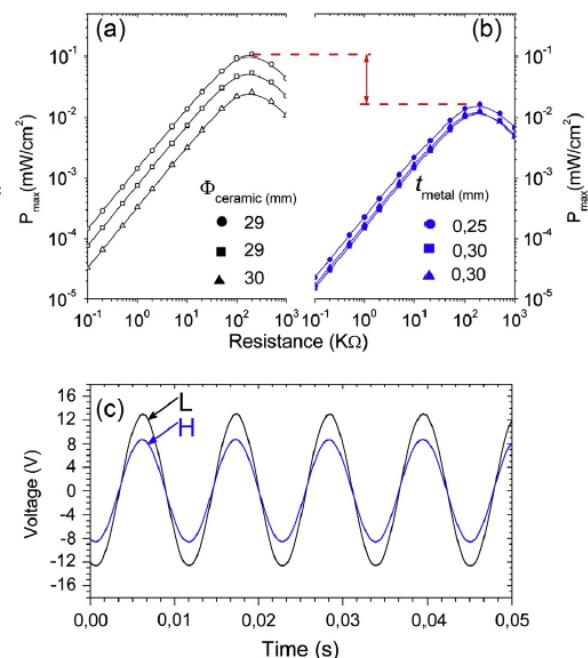
Piezoelectric cymbals with a similar design to the one, are fabricated with commercial PZT ceramics (Noliac NCE51 and PiCeramics PIC 141) as piezoelectric components bonded by epoxy (EPO-TEK 353ND-T)



The mechanical excitation is provided by the cars on the road. Their wheels deform the asphalt and excite the cymbals which are embedded in the pavement layers below the road layer.

	Noliac	PI
Diameter (mm)	d	30 29
Relative dielectric constant	$\epsilon_{33}^T/\epsilon_0$	1850 1250
Dielectric loss factor	$\tan \delta (10^{-4})$	190 50
Coupling factors	k_p	0.65 0.55
	k_t	0.51 0.48
Piezoelectric charge constants (10^{-12} C/N)	$-d_{31}$	195 140
	d_{33}	460 310
Piezoelectric voltage constants (10^{-3} V m/N)	$-g_{31}$	13 13.1
	g_{33}	27 29
Mechanical quality factor	Q_m	80 1500
Curie temperature	T_c	340 295

the metal internal diameter, d_{Mi} , is kept constant at a value 5 mm; the **metal thickness (t_M) is at 0.25** and 0.30 mm, while **the metal external diameter (D_{Mi}) is 17 mm**. On the other hand, **the ceramic material thickness, $t_c = 1$ mm**, while its **diameter (D_c) is 29** and 30 mm. Finally, another parameter evaluated is the **cymbals cavity heights (h_{cav}) which is set as 0.25 and 1 mm**. The notation L, H in this manuscript denotes $h_{cav} = 0.25$ and 1.00 mm,



หน่วยปฏิบัติการพิโซอิเล็กทริก



Memorandum of Understanding



ดร. หรรษกร วรรธนะสาร
อาจารย์ที่ปรึกษา



นายจักษุ กองพิมาย
นักวิจัย



นายวัฒนา โพธิ์ตันคำ
นักวิจัย



นส. อรพรรณ เหงหมulin
ป. โภ พิสิกส์



นายรณชัย อินทรครุ
ป. ตรี พิสิกส์



นายรัชชัย เงินนาม
ป. ตรี พิสิกส์

Piezoelectric Research Laboratory

Roadmap 2015-2020



Flexible &
plastic
piezoelectric

Tape casting
Piezoelectric ceramic
thick film 100-300 μm in type of
mono layer and bilayer

Bulk & Piezoelectric properties
PZT-PFN, PFN-PT-Zn,
Dielectric, poling high voltage
and d₃₃ coefficient



Bulk

Piezoelectric
properties

Ferroelectric
properties

Tape casting

Piezoelectric
device

Flexible
& plastic
piezoelectric

2020

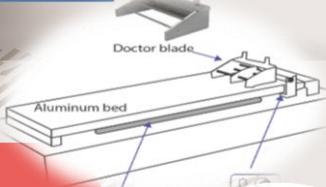
2019

2018

2017

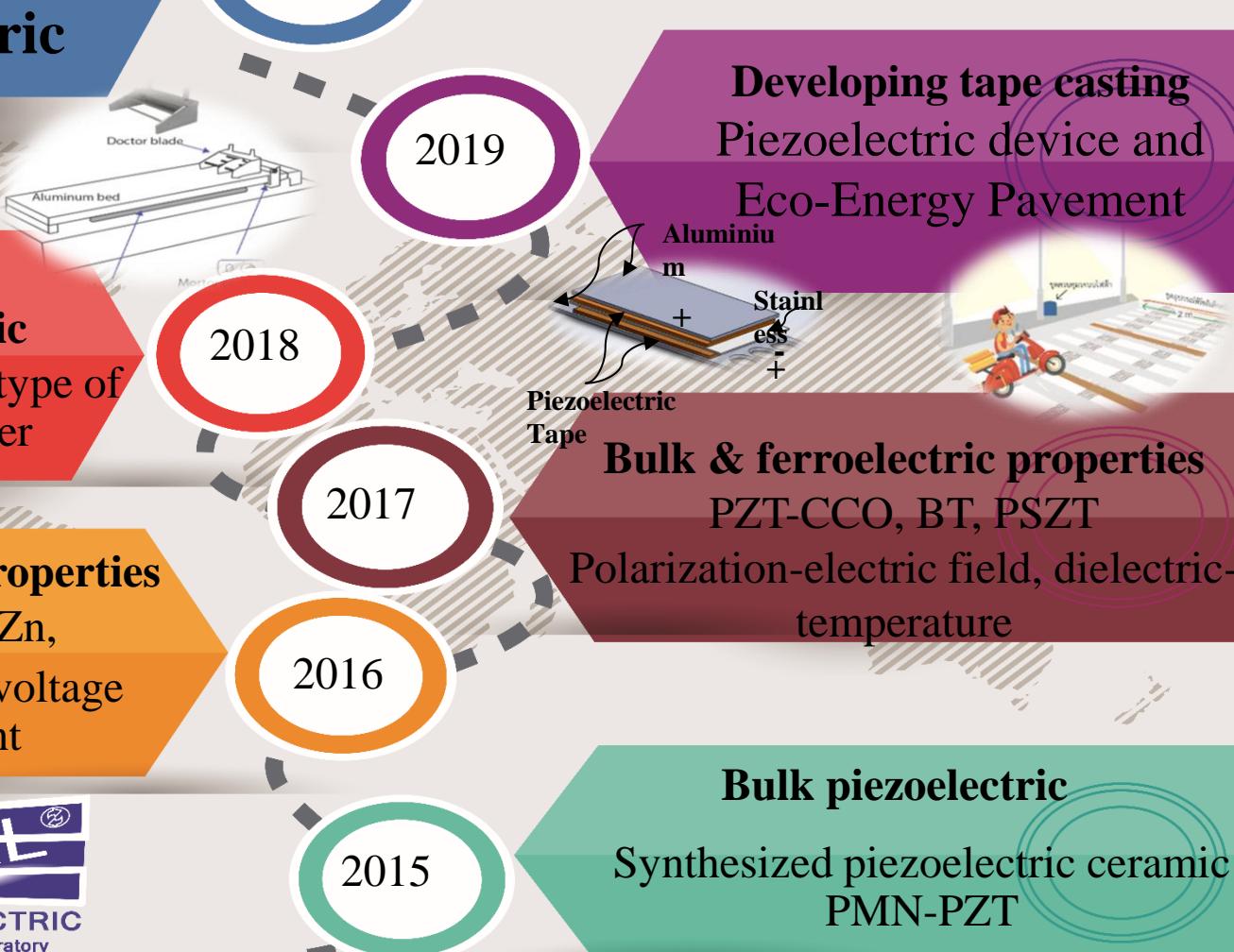
2016

2015



Bulk & ferroelectric properties
PZT-CCO, BT, PSZT
Polarization-electric field, dielectric-
temperature

Bulk piezoelectric
Synthesized piezoelectric ceramic
PMN-PZT



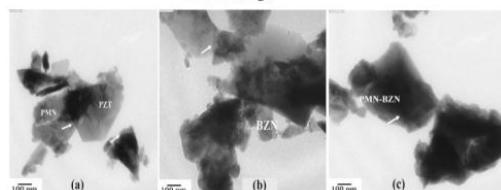
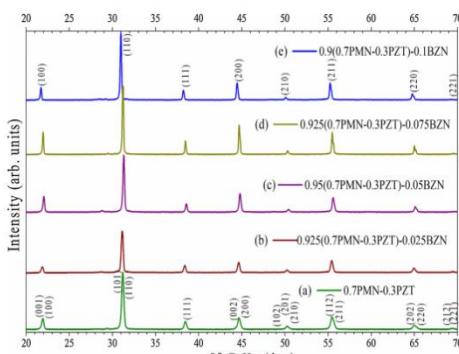
Synthesis

Materials

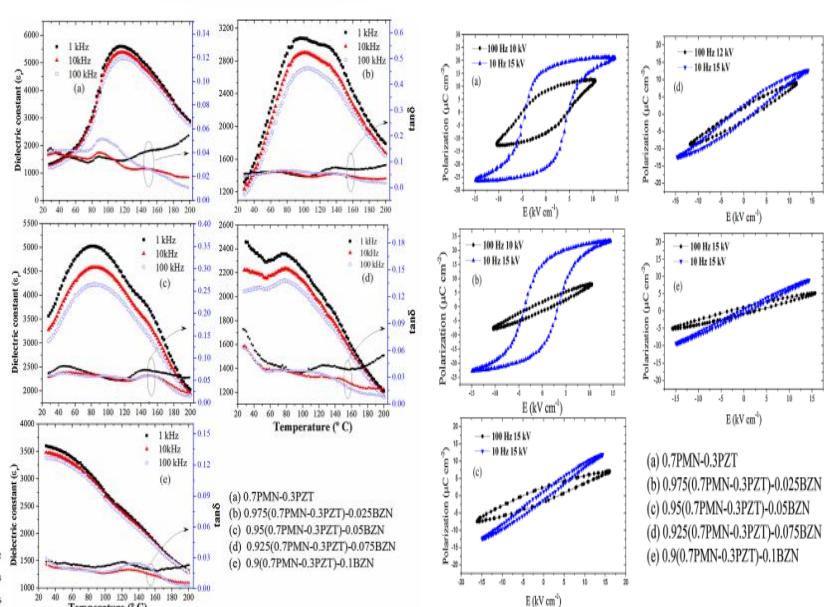
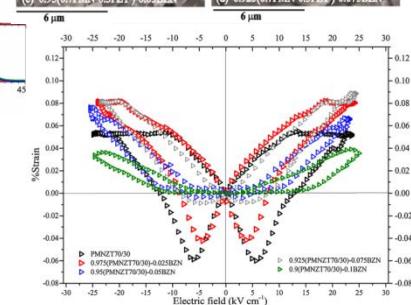
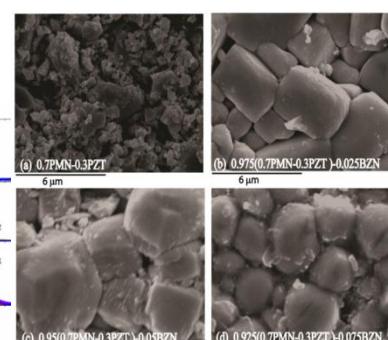
PZT type : PMNZT, PSZT

free-lead type : BZN, KNNL, BT, BSCZT

Method



Solid State Reaction

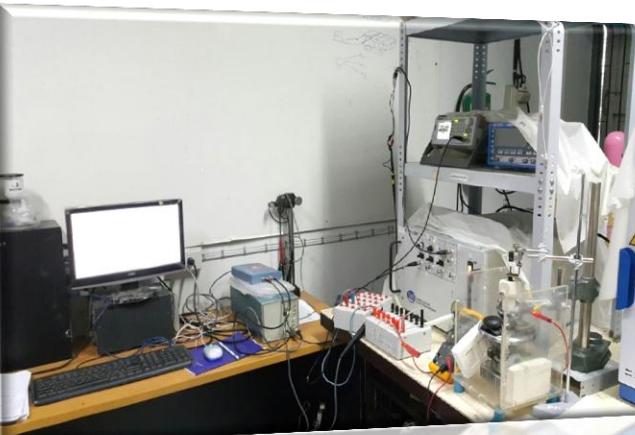


- (a) 0.7PMN-0.3PZT
- (b) 0.975(0.7PMN-0.3PZT)-0.025BZN
- (c) 0.95(0.7PMN-0.3PZT)-0.05BZN
- (d) 0.925(0.7PMN-0.3PZT)-0.075BZN
- (e) 0.9(0.7PMN-0.3PZT)-0.1BZN

Research Instrumentation



Dielectric Constant testing



Hysteresis Electric Loop



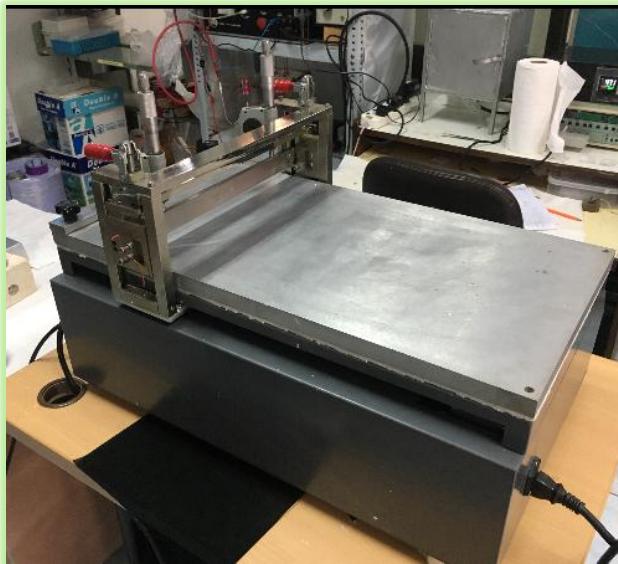
Piezoelectric Coefficient Meter



Piezoelectric
Harvesting
Machine



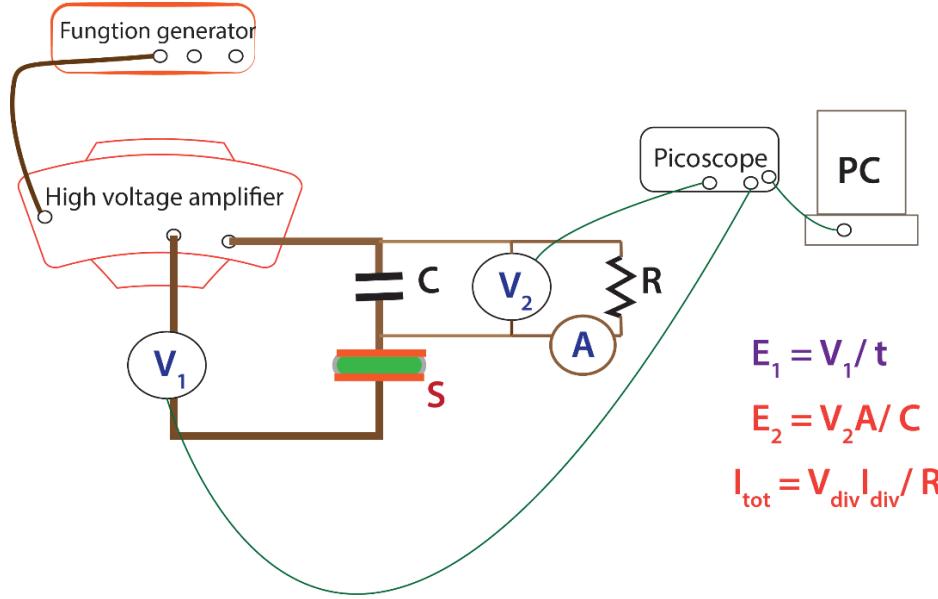
Vacuum mixer



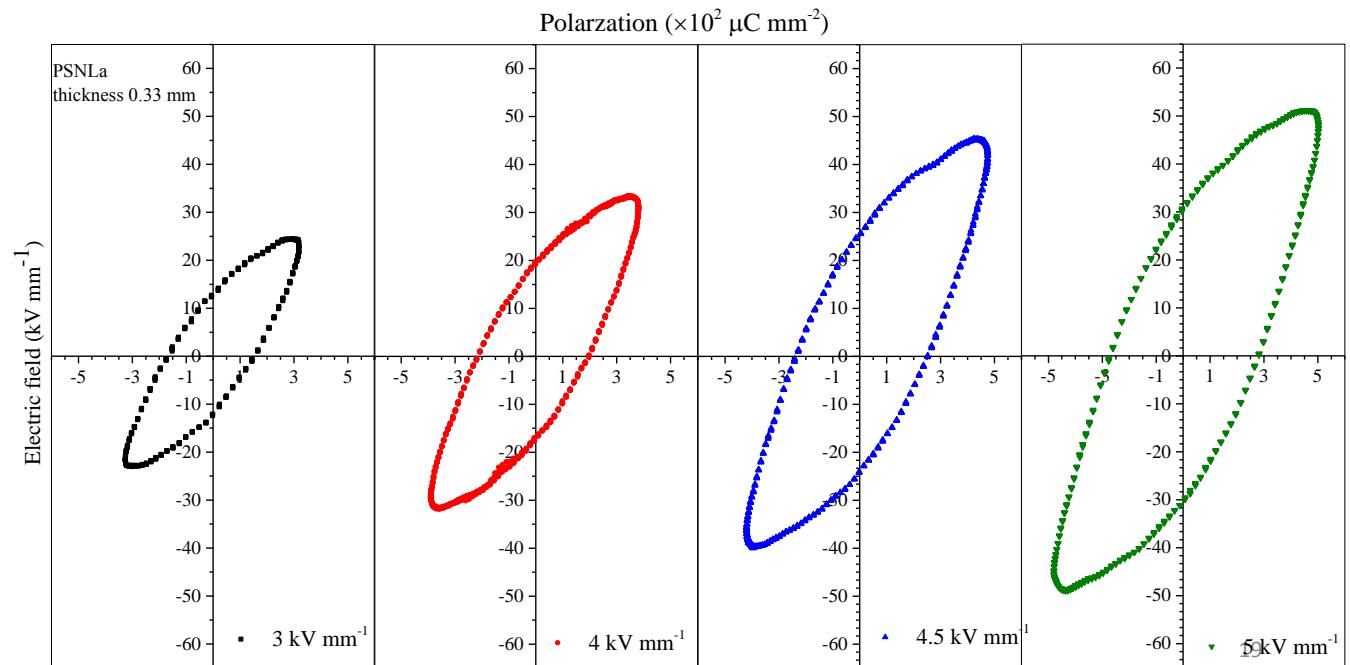
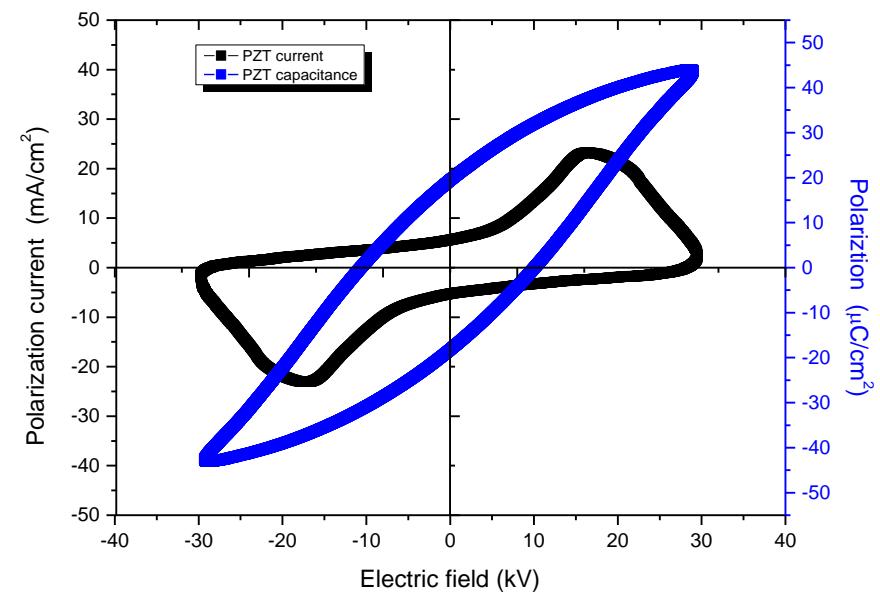
Tape casting



Viscosity meter



P-E curve & I-E curve

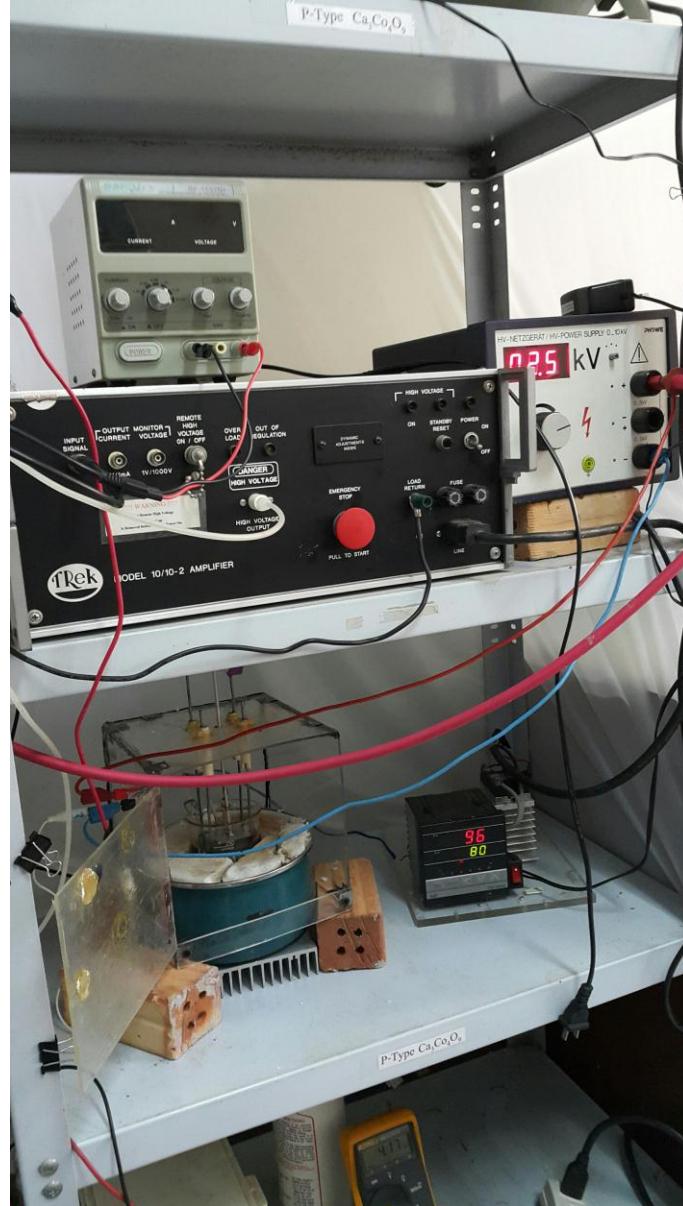




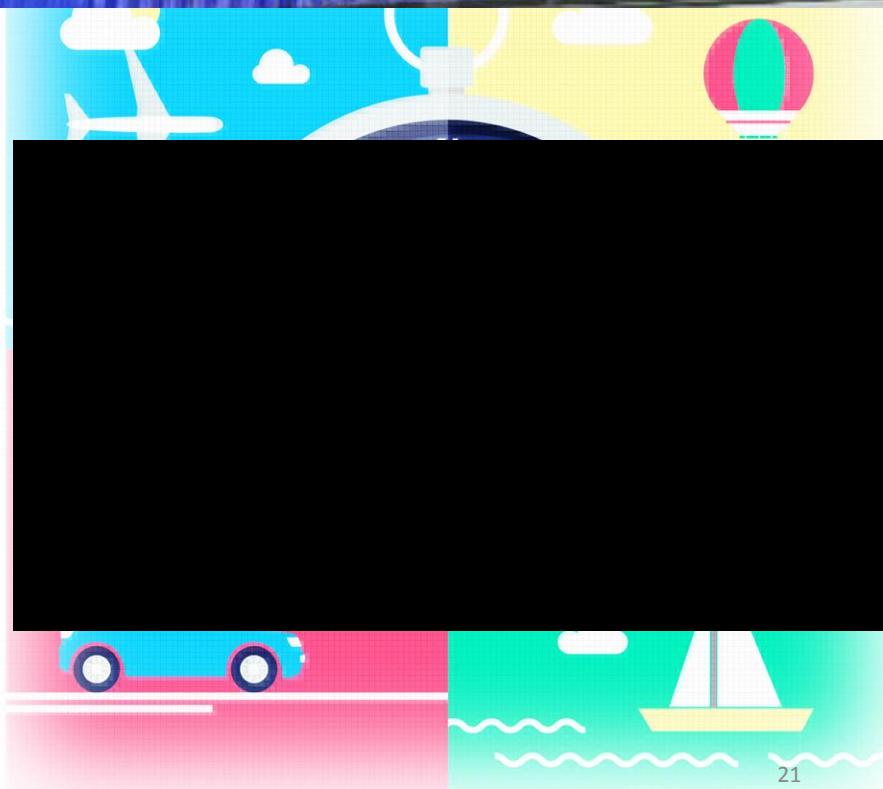
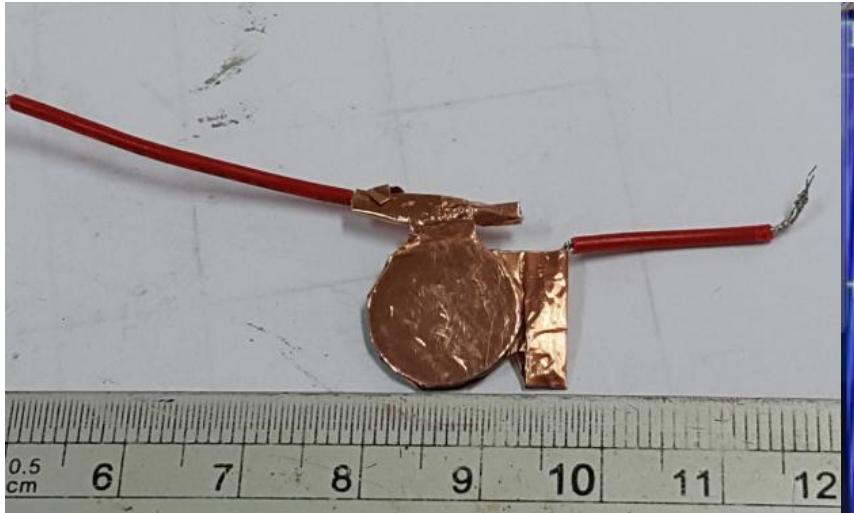
แผ่นเทปจาก การอบ 200 ° C



แผ่นเทปจาก การเผาผนึก 1175 ° C
ความหนา 0.4-0.8 mm



การเหนี่ยววนิวัฟฟ์ 1.5 – 4 kV mm⁻¹



Publication 2017-2018

1. Hassakorn Wattanasarn*, Wattana Photankham, Peeraphat Pattumma & Rattikorn Yimnirun, (2017) Phase transition and dielectric properties of 0.9Pb(Fe_{1/2} Nb_{1/2})O₃-0.1PbTiO₃ ceramics doped with ZnO Pertanika Journal of Science & Technology, Vol. 25 (2) (2017) 527–536. Q3
2. Tosawat Seetawan*, Wattana Photankham, Hassakorn Wattanasarn, Sunti Phewphong, (2017) Influence of nano carbon black added BaTiO₃ on physical and dielectric properties. Materials Today: Proceedings, Vol. 4(5): pp. 6472-6477.
3. Hassakorn Wattanasarn*, Wattana Photankham, Jukrit Kongpimai, Chanchana Thanachayanont and Rattikorn Yimnirun. Effect of ZnO addition on ferroelectric properties of 0.94Pb(Fe_{1/2} Nb_{1/2})O₃-0.06PbTiO₃ and 0.9Pb(Fe_{1/2} Nb_{1/2})O₃-0.1PbTiO₃ ceramics. Integrated Ferroelectrics, 187 (1), (2018) 33-44 <https://doi.org/10.1080/10584587.2018.1445393>, Impact Factor = 0.457, Q3
4. Wattana Photankham, Jukrit Kongpimai, Sunti Phewphong, Hassakorn Wattanasarn*, Suvich Samapisut, and Achara. Namthaisong. Effect of PFN addition on microstructure and piezoelectric properties of PZT58/42 ceramics. Integrated Ferroelectrics, Vol. 187 (1), (2018) . 80-88. <https://doi.org/10.1080/10584587.2018.1445685>, Impact Factor = 0.457, Q3
5. Jukrit Kongpimai, Wattana Photankham, Achara. Namthaisong, Sunti Phewphong, Hassakorn Wattanasarn*. Dielectric and ferroelectric properties of Pb(Zr_{0.53}Ti_{0.47})O₃ ceramics modified with Sr. Integrated Ferroelectrics, 187(1) (2018), 14-19. <https://doi.org/10.1080/10584587.2018.1445357>. Impact Factor = 0.457, Q3
6. Sunti Phewphong, Wattana Photankham, Jukrit Kongpimai, Chanchana Thanachayanont and Rattikorn Yimnirun. Dielectric and ferroelectric properties of Pb(Fe_{1/2} Nb_{1/2})O₃ modification on Pb(Zr_{0.52}Ti_{0.48})O₃ ceramics. Integrated Ferroelectrics, 187:(1) (2018), 89-99. <https://doi.org/10.1080/10584587.2018.1445687>, Impact Factor = 0.457, Q3.

Thank you for your attention

